## NSN 5961-01-325-0453

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-325-0453 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** Between 0.250 inches and 0.328 inches Overall Width: Between 0.990 inches and 1.050 inches **End Application:** Indicator group an/spa-25g **Mounting Facility Quantity:** 2 **Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole Field Force Effect Type: Electrostatic charge **Features Provided:** Hermetically sealed case and electrostatic sensitive **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 drain to source voltage **Current Rating Per Characteristic:** 8.00 amperes source cutoff current of standard range **Power Rating Per Characteristic:** 40.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure:** 

**Demilitarization:** 

No

## **NSN 5961-01-325-0453** Transistor - Page 2 of 2



Fiig:

A110a0